NSN 5961-01-091-5095

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View Online at https://aerobasegroup.com/nsn/5961-01-091-5095 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage, dc and 100.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 250.00 milliamperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** A heat sink is attached to transistor; junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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